Diode Semiconductor Device - Page 1 of 1



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| | osure Material: |
|--------|---|
| Glas | - |
| | rall Length: |
| | 8 inches |
| | ninal Length: |
| 1.00 | 0 inches |
| Ove | rall Diameter: |
| 0.31 | 3 inches |
| Mou | nting Method: |
| Term | ninal |
| Feat | ures Provided: |
| Hern | netically sealed case |
| Sem | iconductor Material: |
| Silico | on |
| Volta | age Rating In Volts Per Characteristic: |
| 8.4 | regulator voltage |
| Curr | ent Rating Per Characteristic: |
| 10.0 | 0 milliamperes repetitive peak forward current |
| Max | imum Operating Tempurature Per Measurement Point: |
| 125. | 0 degrees celsius ambient air |
| Tern | ninal Type And Quantity: |
| 2 un | insulated wire lead |
| Shel | f Life: |
| N/a | |
| Unit | Of Measure: |
| | |
| Dem | ilitarization: |
| No | |
| Fiig: | |
| A11(|)a0 |